1000 nm band 10 GHz Intensity Modulator

#### Modulator



The NIR-MX-LN-10 is an intensity modulator especially designed for operation in the 1000 nm wavelength band.

This Mach-Zehnder modulator offers engineers working at 1000 nm the intrinsic and unparalleled benefits of  $LiNb0_3$  external modulation: high bandwidth, high contrast up to 30 dB and beyond, ease of use. Thanks to Photline Technologies proprietary waveguide process, the NIR-MX-LN-10 exhibits a stable behaviour and supports several tens mW of input optical power.

#### **FEATURES**

- Superior Extinction ratio: > 30 dB
- High Bandwidth ( > 12 GHz)
- X-cut for high stability
- Low drive voltage
- Low insertion loss

#### **APPLICATIONS**

- Pulse generation / picking
- Carrier suppression
- Fiber optics sensors
- Pulse applications
- Analog transmission

#### **OPTIONS**

- 20 GHz version
- 1550 nm, 1300 nm band versions
- Choice of optical connectors

#### **RELATED EQUIPMENTS**

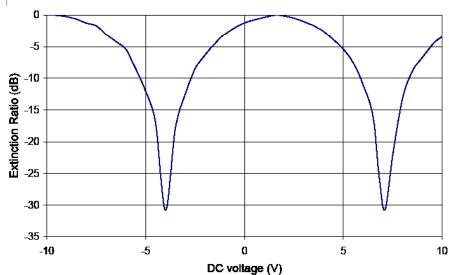
- RF amplifiers
- MBC-DG Automatic Bias Controllers

### **Performance Highlights**

Parameter	Min	Тур	Max	Unit
Operating wavelength	980	-	1150	nm
Insertion loss	-	5	-	dB
Extinction ratio	-	30	-	dB
Electro-optical bandwidth	-	12	-	GHz
Vp RF @50 kHz	-	4	-	V
Electrical return loss	-	12	-	dB

Specifications given at 25 °C, 1060 nm

## **Extinction Ratio Response**





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### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Electro-optic bandwidth	S <sub>21</sub>	RF electrodes, from 2 GHz	10	12	-	GHz
Ripple S <sub>21</sub>	ΔS21	RF electrodes, f ← 12GHz	-	0.5	1	dB
Electrical return loss	ES <sub>11</sub>	RF electrodes	-	-12	-10	dB
Vπ RF @50 kHz	VπRF <sub>50 kHz</sub>	RF electrodes	-	4	5	V
$V\pi$ DC electrodes	VπDC	DC electrodes	-	5	6	V
RF input impedance	Z <sub>in-RF</sub>	-	-	40	-	Ω
DC input impedance	Z <sub>in-DC</sub>	-	-	1	-	ΜΩ

# **Optical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Crystal	-	-		Lithium Niobat	e X-Cut Y-Prop	
Operating wavelength	l	-	980	1060	1150	nm
Insertion loss	IL	Without connectors	-	5	5.5	dB
DC extinction ratio	ER > 20	Measured with narrow source linewidth < 200 MHz	20	-	-	dB
	ER > 25		25	-	-	dB
	ER > 30		30	-	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	α	-	-0.1	0	0.1	-

All specifications given at 25  $^{\circ}\text{C}\text{, }850~\text{nm}\text{, }\text{unless differently specified}$ 

# **Absolute Maximum Ratings**

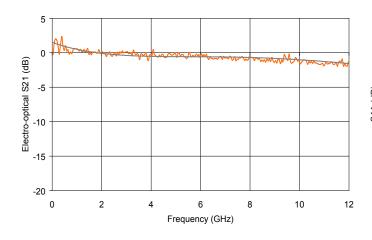
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

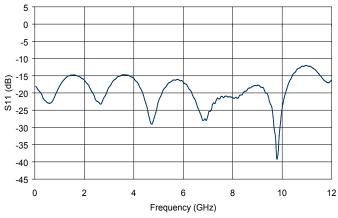
Parameter	Symbol	Min	Max	Unit
RF input power	EP <sub>in</sub>	-	28	dBm
Bias voltage	V <sub>bias</sub>	-20	+20	V
Optical input power	0P <sub>in</sub>	-	20	dBm
Operating temperature	ОТ	0	+70	°C
Storage temperature	ST	-40	+85	°C

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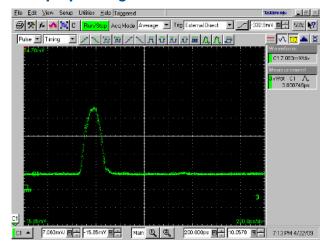
### Modulator

### S21 & S11 Parameter Curves at RF input port

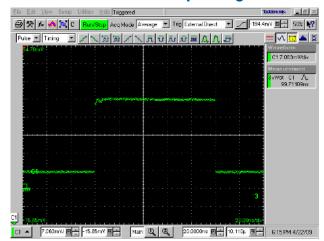




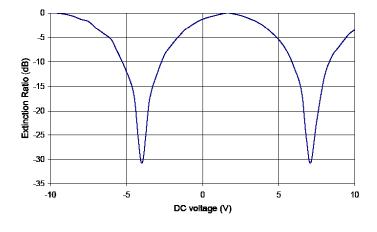
## 100 ps pulse generated



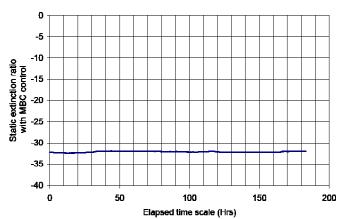
## 100 ns pulse generated



#### **Extinction Ratio**



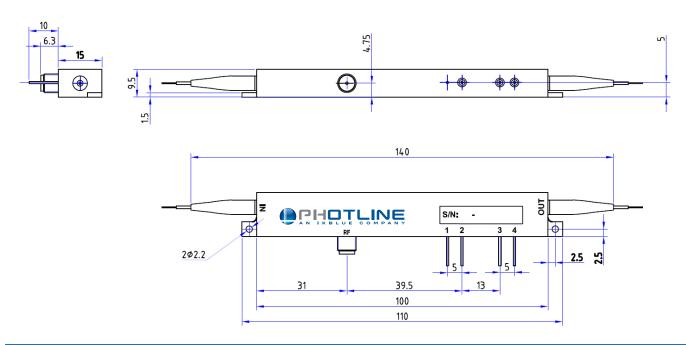
# **Stability with Time and Temperature**



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## Mechanical Diagram and Pinout All measurements in mm



Port	Function	Note
IN	Optical input port	Polarization maintaining fiber, Corning PM 98-U25A, Length 1.5 meter. Buffer diameter 900 mm
OUT	Optical output port	Polarization maintaining fiber, Corning PM 98-U25A, Length 1.5 meter. Buffer diameter 900 mm
RF	RF input port	Wiltron female K
1	Ground	Pin feed through diameter 1.0 mm
2	DC	Pin feed through diameter 1.0 mm
3	Photodiode cathode	Pin feed through diameter 1.0 mm
4	Photodiode anode	Pin feed through diameter 1.0 mm

# **Ordering information**

# NIR-MX-LN-BW-XX-Y-Z-AB-CD-xxdB

BW = Bandwidth : **10** 10 GHz **20** 20 GHz

XX = Internal photodiode : **00** Not integrated PD PD Integrated
Y = Input fiber : P Polarisation maintaining S Standard single mode
Z = Input fiber : P Polarisation maintaining S Standard single mode
AB = Output connector : 00 bare fiber FA FC/APC FC FC/SPC
CD = Output connector : 00 bare fiber FA FC/APC FC FC/SPC
Note : optical connectors are Senko with narrow key or equivalent

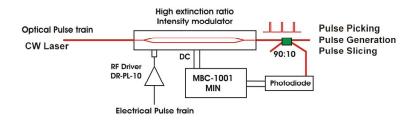
xxdB = Extinction ratio: 20 20 dB 25 25dB 30 30dB

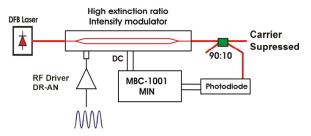


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#### Related equipments





## Pulse Generation / Picking / Slicing

DR-PL amplifiers series are intended to drive NIR-MX-LN as to generate undistorted optical pulses.

MBC-DG-BT is an automatic bias controller designed to lock the operating point of the NIR-MX-LN modulators. MBC-DG-BT achieves an extinction ratio up to 50 dB with the proper modulator.



### Carrier suppressed / Analog modulation

DR-AN amplifiers series are a wideband RF amplifiers modules designed for analog applications at frequencies up to 40 GHz.



MBC-DG-BT is an automatic bias controller designed to lock the operating point of the NIR-MX-LN modulators.



Modbox-Pulse Modbxes are a family of turnkey optical transmitters and external benchtop units for pulse and other specific applications.

Pulse Genration / Pulse Picking / Slicing ModBoxes are Optical Modulation Units designed to generate controlled optical pulses.

#### **About us**

Photline is a member of the **iXBlue** group of companies and a provider of Fiber Optics Modulation Solutions based on the company LiNb0<sub>3</sub> modulators and high-speed electronics modules. Photline Technologies offers high speed and high data rate modulation solutions for the telecommunication industry and the defense, aerospace, instruments and sensors markets. The products offered by the company include: comprehensive range of intensity and phase modulators (800 nm, 1060 nm, 1300 nm, 1550 nm, 2000 nm), RF drivers and modules, transmitters and modulation units.

ZI Les Tilleroyes - Trépillot 16, rue Auguste Jouchoux - 25 000 Besançon - FRANCE Tel. : +33 (0) 381 853 180 - Fax : +33 (0) 381 811 557 Photline reserves the right to change, at any time and without notice, the specifications, design, function or form of its products described herein. All statements, specification, technical information related to the products herein are given in good faith and based upon information believed to be reliable and accurate at the moment of printing. However the accuracy and completeness thereof is not guaranteed. No liability is assumed for any inaccuracies and as a result of use of the products. The user must validate all parameters for each application before use and he assumes all risks in connection with the use of the products